Mechanical response of indium micro-joints to low temperature cycling

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Abstract
In this study, mechanical properties of indium micro-joints exposed to low temperature cycling were investigated. The metallization structure of Ni/Cu was specially used as a substrate to form indium joints for mechanical tests. This paper focuses mainly on the tensile test of indium joints at thermal cycling from 300 K to 77 K. The Young’s modulus, the ultimate strength and yield strength of the material were obtained. The failure mode after different loading histories was analyzed. The results indicate the decline of the Young’s modulus with the increase in the number of thermal cycles; however, the ultimate/yield strength of indium joints did not show an obvious trend with the number of thermal cycling. It was confirmed that indium joints still maintain a high ductility even after 20 thermal cycles. Finally, the associated modeling provides an insight predicting that an interface between indium and copper could be the potential site for failure in thermal cycling.

Keywords: Indium; the liquid nitrogen temperature; reliability

1. Introduction
Indium is of considerable interest for applications in electronics packaging due to its excellent plasticity and self-alignment capability. Indium has been widely used in flip chip interconnections, which can offer high I/Os, fine pitch and small bumps (< 20 μm). In particular, a mismatch of coefficients of thermal expansion between a substrate and the connected chip, which is one of the most critical reliability issues in flip chip assembly, can be accommodated due to indium’s excellent ductility [1]. Furthermore, soldering with indium is considered as a low-temperature process, which has been lately employed in a number of applications, such as 3D wafer stacking. A typical application is using the indium bump-bonding for the electronics integration of hybrid pixel detectors. Such detectors comprise a crystalline semiconductor that is often bump-bonded to a pixelated application specific integrated circuit (ASIC) readout chip. It is within this context that the reliability issues associated with service conditions of the hybrid pixel detector were concerned in terms of functioning in a harsh environment, namely, at significant temperature variations - from the room temperature to the liquid nitrogen temperature [2]. The objective of this paper is to investigate the microstructure and mechanical properties of indium micro-joints during the low temperature cycling between 300 K and 77 K.

Some investigations on the low-temperature properties of bulk indium metal have been relatively well documented. The studies of the tensile behaviour of indium by Reed et al. [3] identified the strain-hardening and deformation-twinning characteristics at 4.10 K and 76 K. Mechanical twinning in indium was reported by Remaut et al. [4] and Becker et al. [5], reviewed by Hall [6], and studied in In-Th alloys by Wuttig and Lin [7]. Elastic properties of indium were determined by Kim and Ledbetter [8], with the Young’s modulus magnitudes of 12.61 GPa at 300 K, 18.36 GPa at 80 K and 19.56 GPa at 5 K. Some compressive data on stress-strain characteristics of indium at low temperature were also obtained by Swenson [9] in the study of its compressibility. However, all of these investigations were based on tests of bulk specimens of indium or its alloys. The low-temperature properties of indium joints at a microscopic scale are expected to be different since the dimensions of indium joints are reduced to a length scale, at which mechanical and fatigue properties of each grain can have a significant influence on overall reliability due to the anisotropic characteristics. Therefore, it is important to understand the mechanical behavior of such indium micro-joints at low temperature under conditions close to those of the joints used in the hybrid pixel detector.

2. Experimental details
2.1 Material
The tensile specimens of indium micro-joints were prepared in a metalized copper substrates with a multilayered structure of Cu/Ni/In/Ni/Cu. The indium was received from the Indium Corporation as ingots, which were rolled into the thin sheets as-required dimension with certain thickness. As copper is one of the most common substrate used in the electronics packaging, high purity copper (Cu) with 1 mm thickness was used as the substrate for the fabrication of tensile testing specimens with the inserts of thin layer of indium. Nickel (Ni) was electroplated on the copper substrate prior to the indium soldering in order to minimize the effects of the Cu-In intermetallic compounds on the mechanical behavior of such indium micro-joints. Although Au/Ni/Cu is commonly used as the main substrate and metallization for the electronics integration of hybrid pixel detectors, it was recognized that the high diffusion of Au into the indium joints may become a concern for reliability. The electroplating apparatus use for nickel metallization is shown in Figure 1; it consists of the computer control system, power supply and electroplating cell. The electrolytic solution is made of nickel sulfamate and the boric acid.
2.2 Procedures

The tensile specimens were prepared with the specific micrometer-driven device in order to control the thickness of the joint between two Ni layers as shown in Figure 2. This is to ensure the reliable mechanical data of indium joint. The indium joints were formed between two pieces of electroplated Ni/Cu, the copper substrate are 80 mm×30 mm with 1 mm thickness. For the reflow process, a Planer T-Track© reflow oven was used in the ambient condition. To enable the interfacial reactions, the flux Actiec 5 (Militcore®) was applied to the Ni/Cu substrates prior to the insertion of a thin sheet of indium. After reflow, all the large planar joints were cut into small specimens along the cross-section of the welding line to produce a number of testing samples with a width of approximately 10 mm. The cutting process was performed with a low-speed saw, inducing little mechanical damage to the joints during the cutting process. In this study, indium joints with the thickness of 300 μm were made.

3. Results

3.1 Effect of thermal cycling on tensile properties

The tensile test data after thermal cycling has been collected, which include Young’s modulus, ultimate strength, engineering stress-strain from the indium micro-joint after 20 cycles, and the results are given in Figure 5, 6 and 7.

As seen in Figure 5, the Young’s modulus of indium joint decreases with the increase in the number of thermal cycles. However, the data of the ultimate strength (Figure 6) and the yield strength of indium joint were relatively scattered, with the extent of scatter increasing with the
loading history. This may be attributed to the slight variations of the individual specimens, therefore the deviation did not show a particular trend. Further tests with more specimens are needed to establish such trends; this study is currently ongoing. In terms of the engineering stress-strain relation due to the thermal cycling, indium joints with Ni/Cu still maintain sufficient ductility even after 20 thermal cycles (see in Figure 7). Tests with more thermal cycles are being conducted to analyze this behavior.

![Figure 6 Evolution of Ultimate strength of In/Ni/Cu with thermal cycles](Image)

**Figure 6 Evolution of Ultimate strength of In/Ni/Cu with thermal cycles**

<table>
<thead>
<tr>
<th>Number of thermal cycles</th>
<th>Ultimate strength (MPa)</th>
</tr>
</thead>
<tbody>
<tr>
<td>0</td>
<td>1</td>
</tr>
<tr>
<td>5</td>
<td>2</td>
</tr>
<tr>
<td>10</td>
<td>3</td>
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<tr>
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</tr>
<tr>
<td>20</td>
<td>5</td>
</tr>
<tr>
<td>25</td>
<td>6</td>
</tr>
</tbody>
</table>

![Figure 7 Stress-strain curve of indium joint after 20 cycles](Image)

**Figure 7 Stress-strain curve of indium joint after 20 cycles**

3.2 Possible failure modes of micro-joint of indium due to thermal cycling

Text about the next steps in your analysis

Results for the engineering stress-strain relation of indium joint with thermal cycling suggest that the failure modes of micro-joints of indium even after 20 cycles are prone to plastic failure with obvious hardening and inelastic deformation, such as necking. As shown in Figure 8, the fracture site demonstrates significant plastic deformation, and the brittle fracture appeared after 3 cycles, which mainly occurred at the interface between indium and the Ni/Cu substrate. It should be linked with the mismatch of the coefficients of thermal expansion (CTE) of indium and copper, which was investigated in the modeling and simulation of stress concentration in the indium micro-joint due to thermal cycling as described below.

![Figure 8 Microscopic images of fracture in indium joints with different thermal histories](Images)

**Figure 8 Microscopic images of fracture in indium joints with different thermal histories:** a) after 1 cycle; b) after 3 cycles and c) after 20 cycles

3.3 Numerical analysis of stress concentration in indium micro-joint due to thermal cycling

Based on our experimental work, the effect of thermal cycling from the room temperature to the liquid nitrogen temperature was simulated in order to assist the fundamental understanding of the mechanical behavior of the indium micro-joints. The finite-element software ABAQUS, which is usually used to model the thermo-mechanical behavior of materials, was employed to simulate the stress distribution in the indium/copper (In/Cu) specimen during one thermal cycle. The basic parameters and properties of In and Cu are shown in Table 1.

<table>
<thead>
<tr>
<th>Material</th>
<th>Length/ mm</th>
<th>Width/ mm</th>
<th>Young’s modulus /GPa</th>
<th>Plastic Properties/10^6</th>
<th>Poisson’s ratio</th>
<th>Element type</th>
</tr>
</thead>
<tbody>
<tr>
<td>Indium</td>
<td>10</td>
<td>0.3</td>
<td>12.7</td>
<td>2.8-15.0 with strain variation</td>
<td>0.4498</td>
<td>C3D8R</td>
</tr>
<tr>
<td>Copper</td>
<td>10</td>
<td>30</td>
<td>110</td>
<td>68.95-344.8 with strain variation</td>
<td>0.343</td>
<td>C3D8R</td>
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</tr>
</tbody>
</table>

The modeling results shown in Figure 9 offer a general insight into the character of stress distribution in indium micro-joint when the temperature returned back to the room temperature from liquid nitrogen. Accordingly, the interface between In and Cu is the main location of concerns in terms of the stress concentration, as shown in Figure 10, which shows the match with the results on the possible failure modes for the micro-joint of indium due to thermal cycling. It is worth mentioning that this model was built based on the consideration of hardening with isotropic properties. Since the material properties of indium are anisotropic, rate-dependent and temperature-dependent, not all these parameters required for modeling were available. So the results obtained can provide only a guidance. To best reflect the material behavior, a set of material properties for indium are necessary, and the experimental work is currently carried out to derive such data for future modeling.

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Conclusions

The Young’s modulus of indium micro-joints after thermal cycling was obtained from the tensile test, which showed a decline from 0.04 MPa to 0.021 MPa with the increase in the number of thermal cycles.

The indium joints at micro scale maintain a good ductility even after 20 thermal cycles, indicating that the failure of such joints is not associated with embitterment of indium.

The finite-element simulations illustrate that the interface between indium and copper can be the potential weak site, which could result in the failure of indium joint as due to high stress concentration.

References